

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-40	V
Gate-Source Voltage			V <sub>GSS</sub>	±25	V
Continuous Drain Current (Note 5) $V_{GS} = -10V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-9.1 -7.2	A
Continuous Drain Current (Note 5) $V_{GS}$ = -4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-7.8 -6.2	A
Continuous Drain Current (Note 6) $V_{GS}$ = -10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	-10.1 -8	А
Continuous Drain Current (Note 6) $V_{GS}$ = -4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-8.8 -7	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDM	-100	A
Avalanche Current (Note 7)			I <sub>AS</sub>	-22	A
Avalanche Energy (Note 7)			E <sub>AS</sub>	242	mJ

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	1.45	W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	88	°C/W
Total Power Dissipation (Note 6)	PD	1.82	W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	70	°C/W
Thermal Resistance, Junction to Case (Note 6)	R <sub>θJc</sub>	7.6	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

			_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)			-			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40		_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS			-1	μA	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	IGSS			±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	р		7	11	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -9.8A
	R <sub>DS(ON)</sub>		9	15		$V_{GS} = -4.5V, I_D = -9.8A$
Forward Transfer Admittance	Y <sub>fs</sub>	_	26	_	S	$V_{DS} = -20V, I_D = -9.8A$
Diode Forward Voltage (Note 5)	V <sub>SD</sub>		-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	4234	_	pF	$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz
Output Capacitance	Coss	_	1036	_		
Reverse Transfer Capacitance	Crss	_	526	_		
Gate Resistance	Rg		7.77		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg		47.5	_		V <sub>DS</sub> = -20V, V <sub>GS</sub> = -5V I <sub>D</sub> = -9.8A
Gate-Source Charge	Q <sub>gs</sub>	_	14.2	_	nC	
Gate-Drain Charge	Q <sub>gd</sub>	_	13.5	_		
Turn-On Delay Time	t <sub>D(ON)</sub>		13.2			$\label{eq:VGS} \begin{split} V_{GS} = -10V,  V_{DD} = -20V,  R_g = 6\Omega, \\ I_D = -1A,  R_L = 20\Omega \end{split}$
Turn-On Rise Time	t <sub>R</sub>		10		nc	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		302.7		ns	
Turn-Off Fall Time	t <sub>F</sub>		137.9			

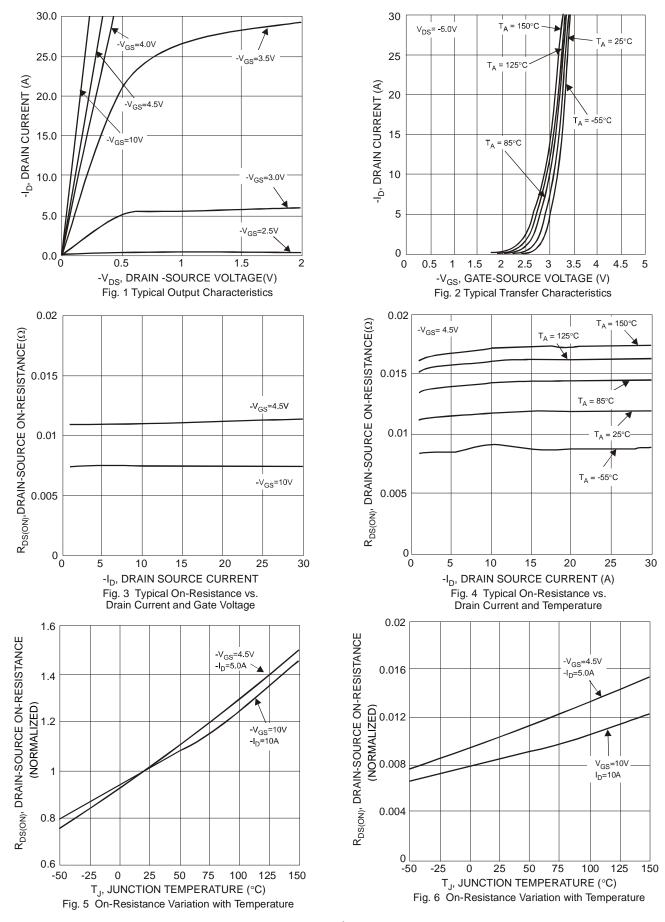
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate. 7 .UIS in production with L = 1mH,  $T_J = +25^{\circ}$ C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

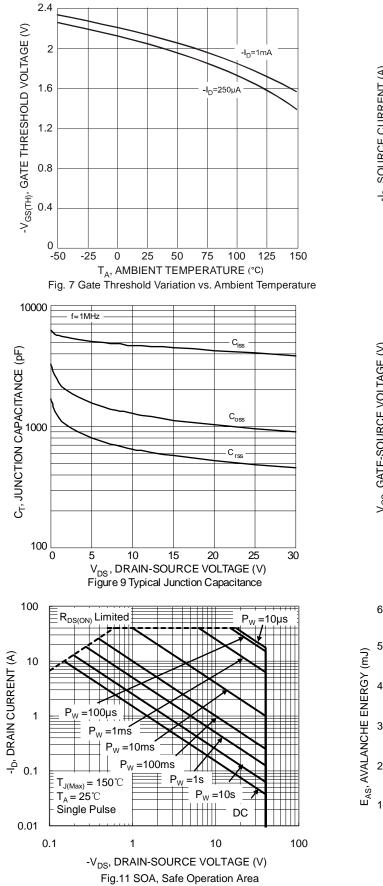
Notes:





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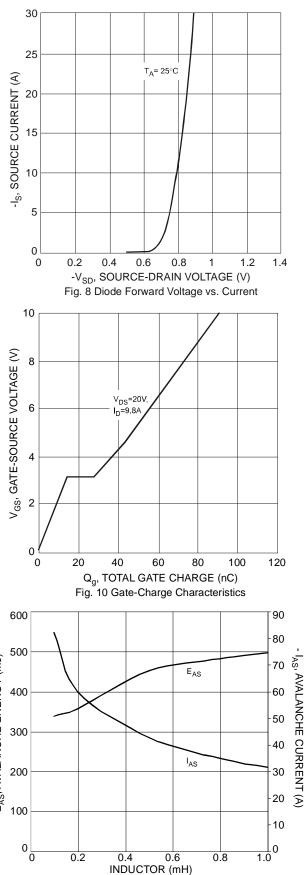
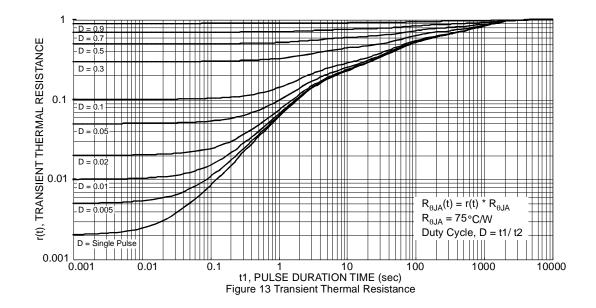


Fig. 12 Single-Pulse Avalanche Tested

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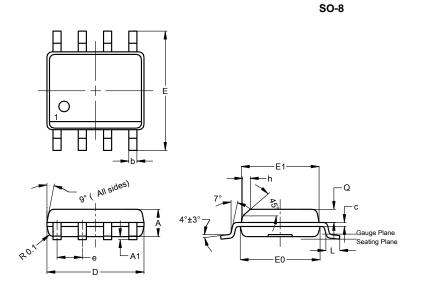






### **Package Outline Dimensions**

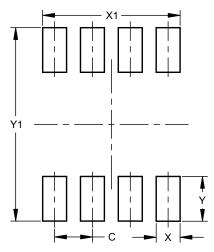
Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h	-		0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	1.27		
Х	0.802		
X1	4.612		
Y	1.505		
Y1	6.50		



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